

**iscN-Channel MOSFET Transistor****TK3R1A04PL, ITK3R1A04PL****• FEATURES**

- Low drain-source on-resistance:  
 $R_{DS(ON)} = 2.5\text{m}\Omega$  (typ.) ( $V_{GS} = 10\text{ V}$ )
- Enhancement mode:  
 $V_{th} = 1.4$  to  $2.4\text{ V}$  ( $V_{DS} = 10\text{ V}$ ,  $I_D = 0.5\text{ mA}$ )
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**• DESCRIPTION**

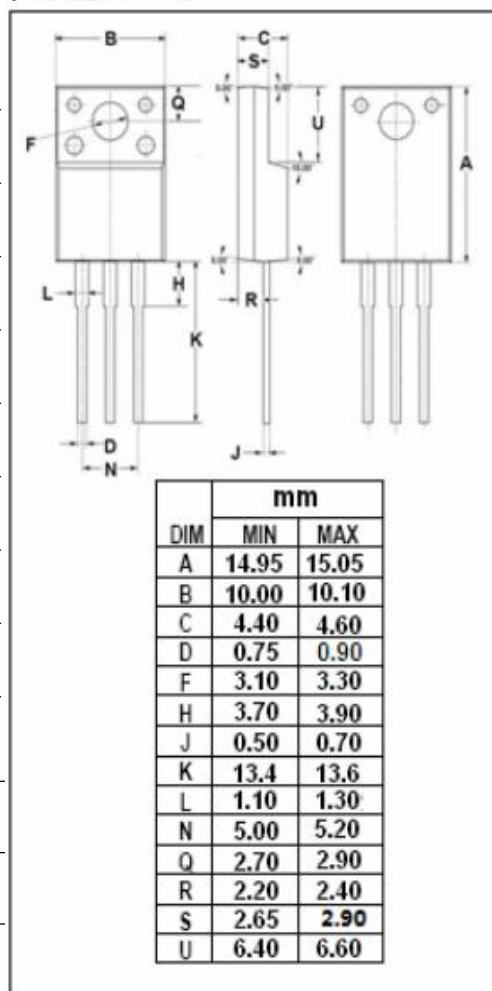
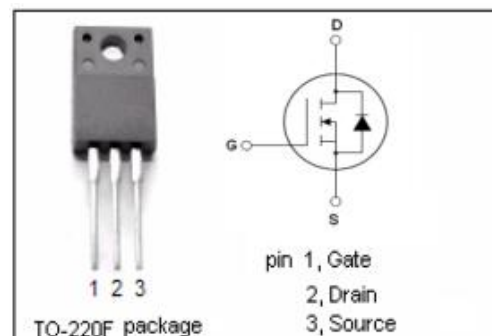
- Switching Voltage Regulators

**• ABSOLUTE MAXIMUM RATINGS( $T_a = 25^\circ\text{C}$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DS}$	Drain-Source Voltage	40	V
$V_{GS}$	Gate-Source Voltage	$\pm 20$	V
$I_D$	Drain Current-Continuous	82	A
$I_{DM}$	Drain Current-Single Pulsed	400	A
$P_D$	Total Dissipation @ $T_c = 25^\circ\text{C}$	36	W
$T_j$	Max. Operating Junction Temperature	175	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-55~175	$^\circ\text{C}$

**• THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	4.16	$^\circ\text{C/W}$
$R_{th(ch-a)}$	Channel-to-ambient thermal resistance	62.5	$^\circ\text{C/W}$



**iscN-Channel MOSFET Transistor****TK3R1A04PL, ITK3R1A04PL****ELECTRICAL CHARACTERISTICS****T<sub>C</sub>=25°C unless otherwise specified**

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 10mA	40			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> =0.5mA	1.4		2.4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 4.5V; I <sub>D</sub> =30A		3.0	3.8	mΩ
		V <sub>GS</sub> = 10V; I <sub>D</sub> =41A		2.5	3.1	
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V; V <sub>DS</sub> = 0V			±0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 40V; V <sub>GS</sub> = 0V			10	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>DR</sub> =82A, V <sub>GS</sub> = 0 V			1.5	V

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